Product data sheet

1. General description

The 74LVC1G11 provides a single 3-input AND gate.

The input can be driven from either 3.3 V or 5 V devices. This feature allows the use of this device in a mixed 3.3 V and 5 V environment.

Schmitt-trigger action at all inputs makes the circuit highly tolerant to slower input rise and fall time.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- 5 V tolerant inputs for interfacing with 5 V logic
- High noise immunity
- Complies with JEDEC standard:
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8-B/JESD36 (2.7 V to 3.6 V)
- ± 24 mA output drive (V_{CC} = 3.0 V)
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Multiple package options
- Specified from –40 °C to +85 °C and –40 °C to +125 °C



3. Ordering information

Table 1. Ordering information							
Type number	Package						
	Temperature range	Name	Description	Version			
74LVC1G11GW	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363			
74LVC1G11GV	–40 °C to +125 °C	SC-74	plastic surface-mounted package (TSOP6); 6 leads	SOT457			
74LVC1G11GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body $1 \times 1.45 \times 0.5$ mm	SOT886			
74LVC1G11GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body $1 \times 1 \times 0.5$ mm	SOT891			
74LVC1G11GN	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm	SOT1115			
74LVC1G11GS	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm	SOT1202			
74LVC1G11GX	-40 °C to +125 °C	X2SON6	plastic thermal extremely thin small outline package; no leads; 6 terminals; body 1 \times 0.8 \times 0.35 mm	SOT1255			

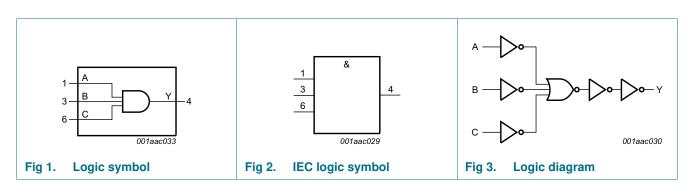
4. Marking

Table 2.Marking

Type number	Marking code ^[1]
74LVC1G11GW	VU
74LVC1G11GV	V11
74LVC1G11GM	VU
74LVC1G11GF	VU
74LVC1G11GN	VU
74LVC1G11GS	VU
74LVC1G11GX	VU

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

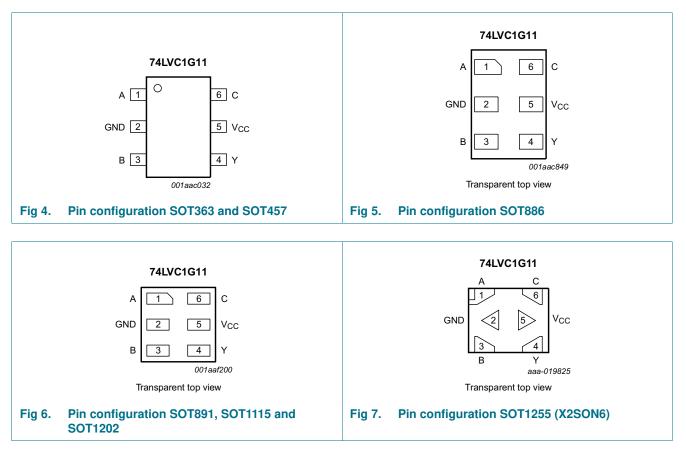
5. Functional diagram



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6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3. Pin description						
Symbol	Pin	Description				
A	1	data input				
GND	2	ground (0 V)				
В	3	data input				
Y	4	data output				
V _{CC}	5	supply voltage				
С	6	data input				

7. Functional description

Table 4. Function table ^[1]			
Input			Output
Α	В	C	Y
Н	Н	Н	Н
L	Х	Х	L
Х	L	Х	L
Х	X	L	L

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+6.5	V
I _{IK}	input clamping current	V ₁ < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+6.5	V
I _{OK}	output clamping current	$V_{\rm O}$ > $V_{\rm CC}$ or $V_{\rm O}$ < 0 V		-	±50	mA
Vo	output voltage	Active mode	<u>[1][2]</u>	-0.5	$V_{CC} + 0.5$	V
		Power-down mode	<u>[1][2]</u>	-0.5	+6.5	V
lo	output current	$V_{\rm O} = 0$ V to $V_{\rm CC}$		-	±50	mA
I _{CC}	supply current			-	100	mA
I _{GND}	ground current			-100	-	mA
P _{tot}	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	<u>[3]</u>	-	250	mW
T _{stg}	storage temperature			-65	+150	°C

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] When $V_{CC} = 0 V$ (Power-down mode), the output voltage can be 5.5 V in normal operation.

[3] For SC-88 and SC-74 packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K. For X2SON6 and XSON6 package: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

9. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		1.65	-	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage	Active mode	0	-	V _{CC}	V
		Power-down mode; $V_{CC} = 0 V$	0	-	5.5	V
T _{amb}	ambient temperature		-40	-	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 1.65 \text{ V} \text{ to } 2.7 \text{ V}$	-	-	20	ns/V
		$V_{CC} = 2.7 \text{ V to } 5.5 \text{ V}$	-	-	10	ns/V

Table 6. Recommended operating conditions

Single 3-input AND gate

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol P	Parameter	Conditions	-40	–40 °C to +85 °C			+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
VIH	HIGH-level	V _{CC} = 1.65 V to 1.95 V	0.65V _{CC}	-	-	0.65V _{CC}	-	V
	input voltage	V _{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	V
		V _{CC} = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
		V _{CC} = 4.5 V to 5.5 V	0.7V _{CC}	-	-	0.7V _{CC}	-	V
VIL	LOW-level	V _{CC} = 1.65 V to 1.95 V	-	-	$0.35V_{CC}$	-	0.35V _{CC}	V
	input voltage	V _{CC} = 2.3 V to 2.7 V	-	-	0.7	-	0.7	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
		V _{CC} = 4.5 V to 5.5 V	-	-	$0.3V_{CC}$	-	0.3V _{CC}	V
V _{OH}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	output voltage	$I_{O} = -100 \ \mu\text{A};$ $V_{CC} = 1.65 \ \text{V} \text{ to } 5.5 \ \text{V}$	V _{CC} - 0.1	-	-	$V_{CC}-0.1$	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.2	1.54	-	0.95	-	V
		$I_{O} = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	2.15	-	1.7	-	V
		$I_{O} = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	2.2	2.50	-	1.9	-	V
		$I_{O} = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.3	2.62	-	2.0	-	V
		$I_{O} = -32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.8	4.11	-	3.4	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	output voltage	I _O = 100 μA; V _{CC} = 1.65 V to 5.5 V	-	-	0.10	-	0.10	V
		I _O = 4 mA; V _{CC} = 1.65 V	-	0.07	0.45	-	0.70	V
		$I_{O} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	0.12	0.30	-	0.45	V
		$I_{O} = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	0.17	0.40	-	0.60	V
		$I_{O} = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	0.33	0.55	-	0.80	V
		$I_{O} = 32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.39	0.55	-	0.80	V
1	input leakage current		-	±0.1	±5	-	±100	μA
OFF	power-off leakage current	$V_{I} \text{ or } V_{O} = 5.5 \text{ V}; V_{CC} = 0 \text{ V}$	-	±0.1	±10	-	±200	μA
lcc	supply current	$V_{I} = 5.5 V \text{ or GND}; I_{O} = 0 A;$ $V_{CC} = 1.65 V \text{ to } 5.5 V$	-	0.1	10	-	200	μA
∆I _{CC}	additional supply current		-	5	500	-	5000	μA
CI	input capacitance	V_{CC} = 3.3 V; V_{I} = GND to V_{CC}	-	4	-	-	-	pF

[1] All typical values are measured at $T_{amb} = 25 \text{ °C}$.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for load circuit see Figure 9.

Symbol	Parameter	Conditions	–40 °C to +85 °C		–40 °C to +125 °C		Unit	
			Min	Typ[1]	Max	Min	Max	
t _{pd}	propagation delay	A, B and C to Y; see Figure 8 [2]						
		V _{CC} = 1.65 V to 1.95 V	1.5	4.7	17.2	1.5	21.5	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.0	3.0	6.2	1.0	7.8	ns
		V _{CC} = 2.7 V	1.0	3.0	6.0	1.0	7.5	ns
		V _{CC} = 3.0 V to 3.6 V	1.0	2.6	4.9	1.0	6.2	ns
		$V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$	1.0	1.9	3.5	1.0	4.4	ns
C _{PD}	power dissipation capacitance	$V_{I} = GND \text{ to } V_{CC}; V_{CC} = 3.3 \text{ V}$ [3]	-	13	-	-	-	pF

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 $f_i = input frequency in MHz;$

 $f_o = output frequency in MHz;$

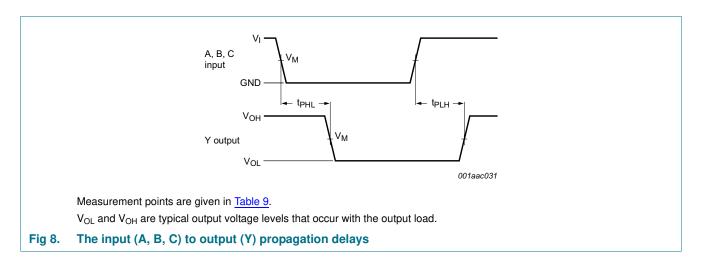
 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}{}^2 \times f_o)$ = sum of the outputs.

12. Waveforms

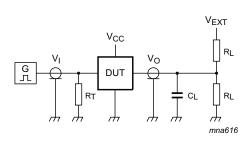


NXP Semiconductors

74LVC1G11

Single 3-input AND gate

Table 9. Measurement points						
Supply voltage	Input	Output				
V _{CC}	V _M	V _M				
1.65 V to 1.95 V	0.5V _{CC}	0.5V _{CC}				
2.3 V to 2.7 V	0.5V _{CC}	0.5V _{CC}				
2.7 V	1.5 V	1.5 V				
3.0 V to 3.6 V	1.5 V	1.5 V				
4.5 V to 5.5 V	0.5V _{CC}	0.5V _{CC}				



Test data is given in <u>Table 10</u>.

Definitions for test circuit:

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_0 of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig 9. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Input	Load		V _{EXT}	
V _{CC}	VI	$t_r = t_f$	CL	RL	t _{PLH} , t _{PHL}
1.65 V to 1.95 V	V _{CC}	\leq 2.0 ns	30 pF	1 kΩ	open
2.3 V to 2.7 V	V _{CC}	≤ 2.0 ns	30 pF	500 Ω	open
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
4.5 V to 5.5 V	V _{CC}	≤ 2.5 ns	50 pF	500 Ω	open

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13. Package outline

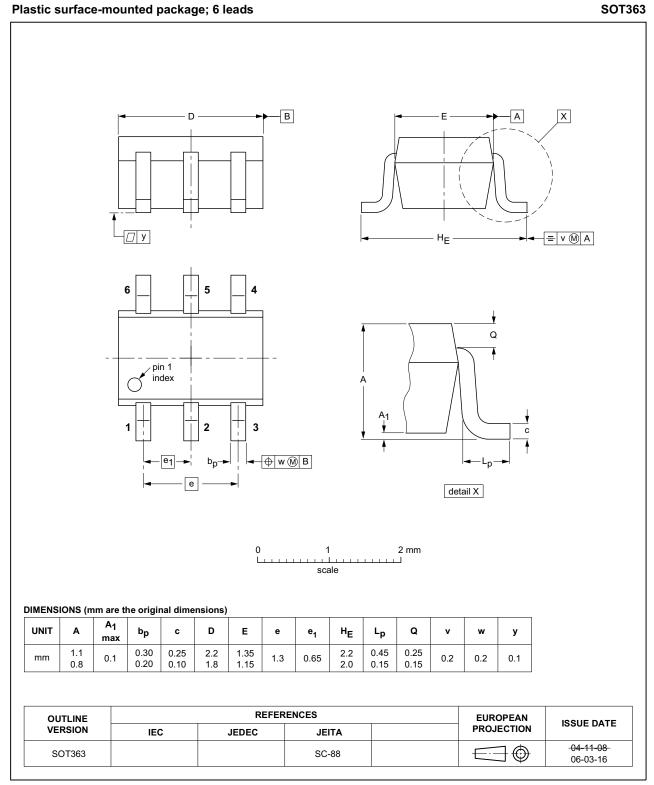


Fig 10. Package outline SOT363 (SC-88)

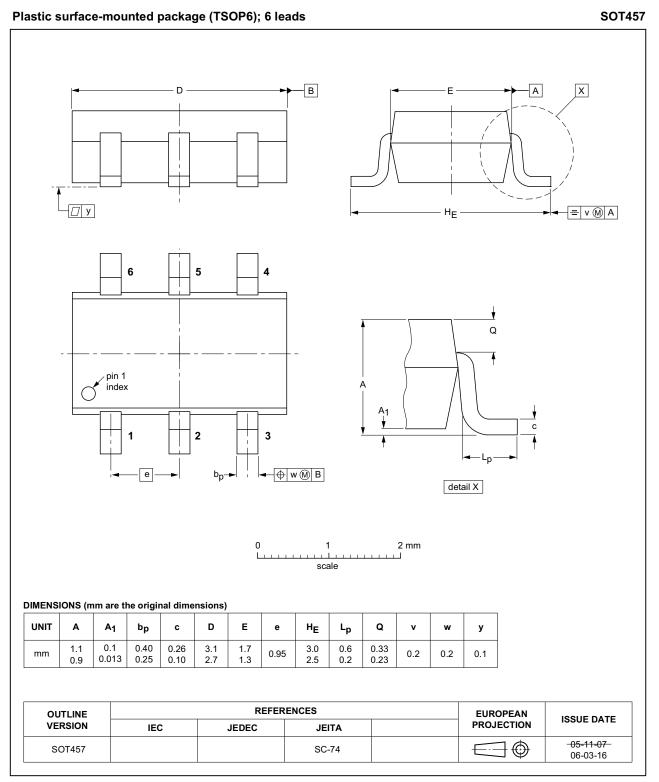
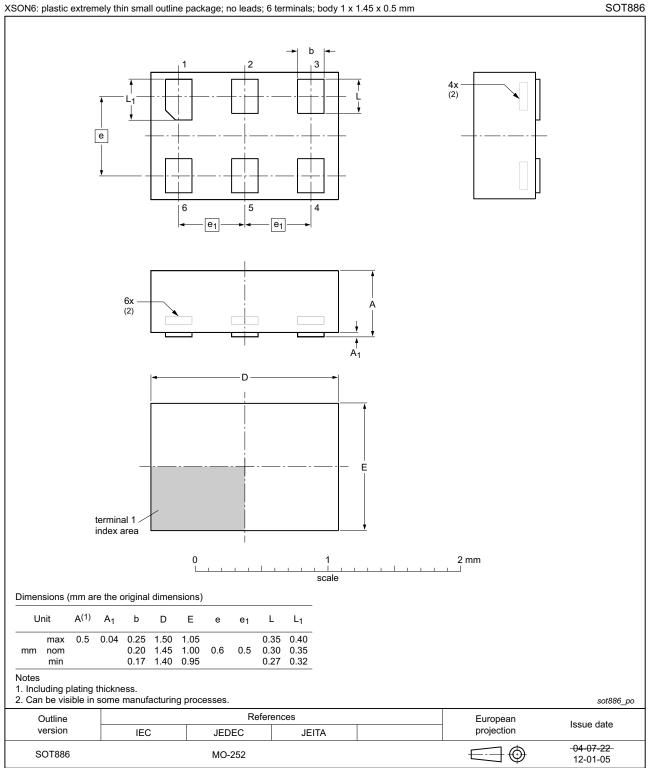


Fig 11. Package outline SOT457 (TSOP6)

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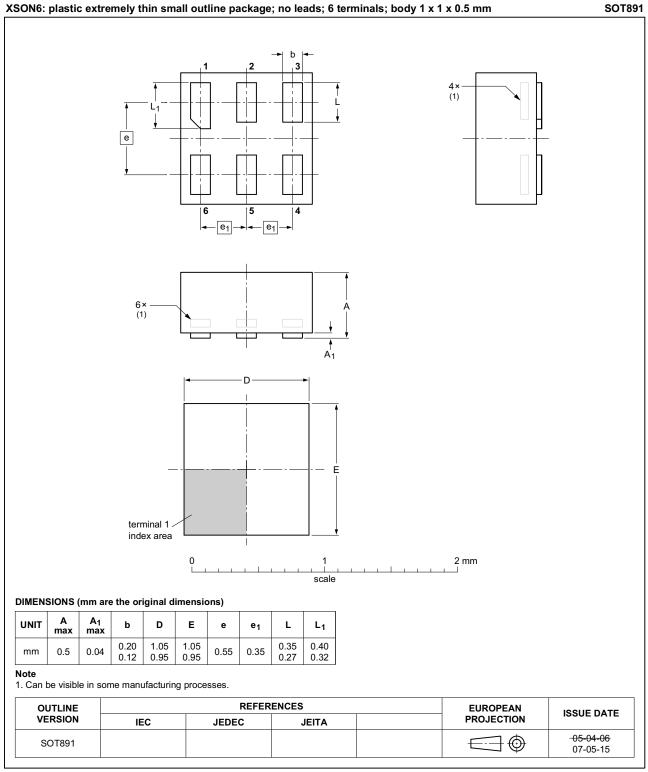


XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

Fig 12. Package outline SOT886 (XSON6)

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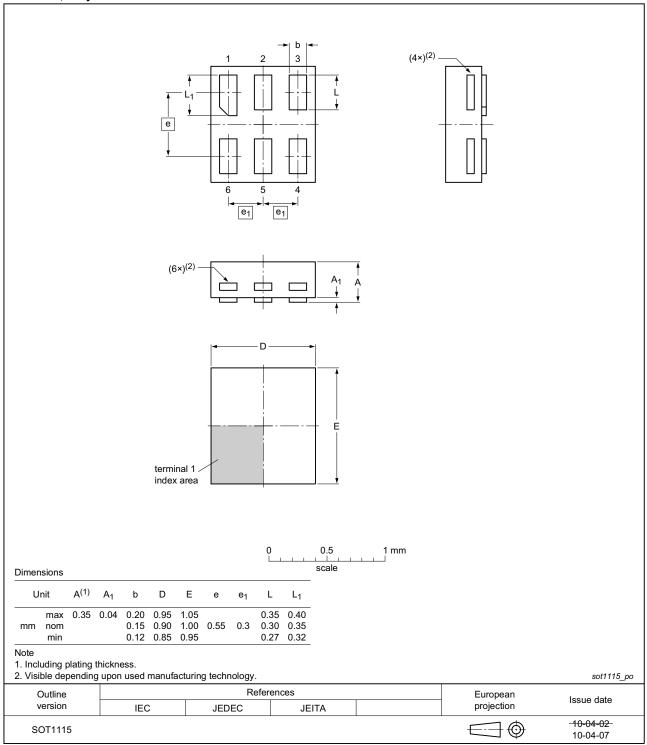
74LVC1G11



XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm

Fig 13. Package outline SOT891 (XSON6)

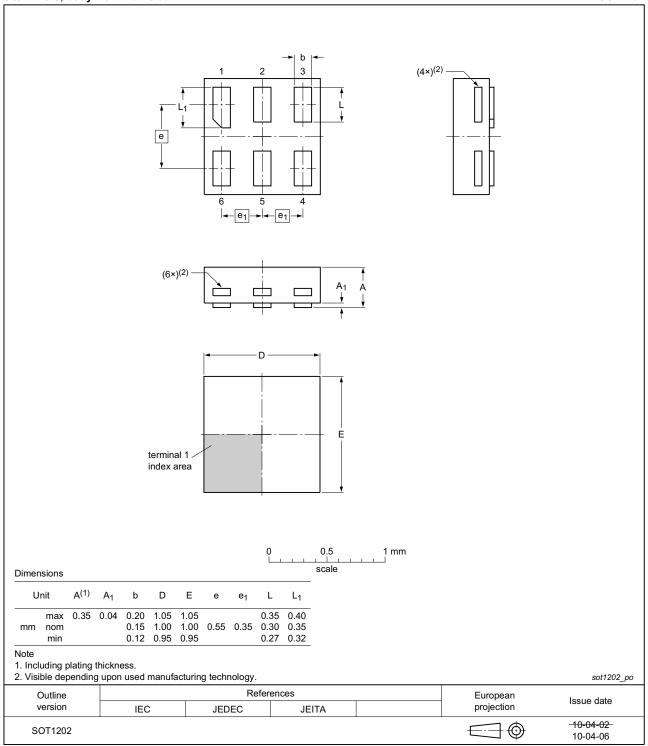
SOT1115



XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm

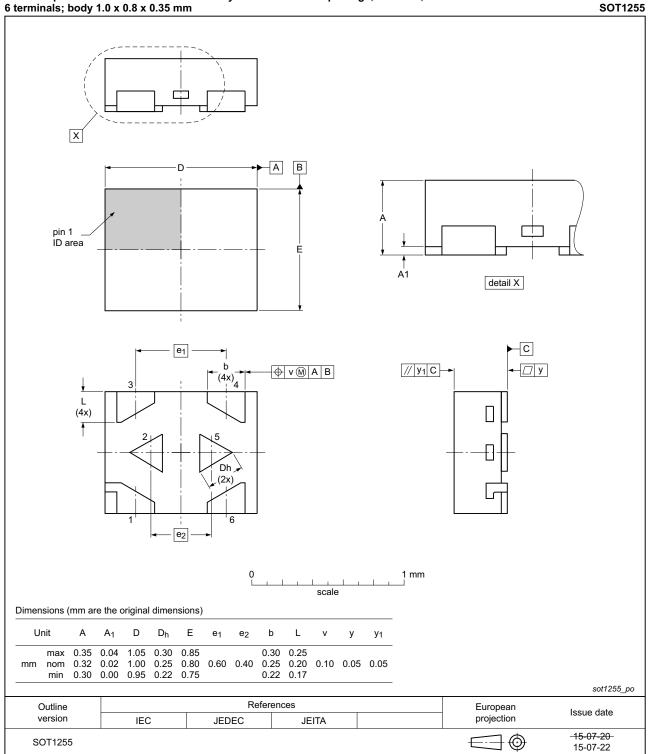
Fig 14. Package outline SOT1115 (XSON6)

SOT1202



XSON6: extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm

Fig 15. Package outline SOT1202 (XSON6)



X2SON6: plastic thermal enhanced extremely thin small outline package; no leads; 6 terminals; body 1.0 x 0.8 x 0.35 mm

Fig 16. Package outline SOT1255 (X2SON6)

14. Abbreviations

Table 11. Abbreviations					
Acronym	Description				
CMOS	Complementary Metal Oxide Semiconductor				
DUT	Device Under Test				
ESD	ElectroStatic Discharge				
НВМ	Human Body Model				
MM	Machine Model				
TTL	Transistor-Transistor Logic				

15. Revision history

Table 12. Revision history								
Document ID	Release date	Data sheet status	Change notice	Supersedes				
74LVC1G11 v.8	20150917	Product data sheet	-	74LVC1G11 v.7				
Modifications:	Added type r	number 74LVC1G11GX (SOT1	255/X2SON6).					
74LVC1G11 v.7	20120704	Product data sheet	-	74LVC1G11 v.6				
Modifications:	 Package out 	Package outline drawing of SOT886 (Figure 12) modified.						
74LVC1G11 v.6	20111209	Product data sheet	-	74LVC1G11 v.5				
Modifications:	Legal pages	updated.	· ·					
74LVC1G11 v.5	20100730	Product data sheet	-	74LVC1G11 v.4				
74LVC1G11 v.4	20070801	Product data sheet	-	74LVC1G11 v.3				
74LVC1G11 v.3	20060906	Product data sheet	-	74LVC1G11 v.2				
74LVC1G11 v.2	20050503	Product data sheet	-	74LVC1G11 v.1				
74LVC1G11 v.1	20041130	Product data sheet	-	-				

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
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74LVC1G11

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Single 3-input AND gate

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74LVC1G11

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Date of release: 17 September 2015 Document identifier: 74LVC1G11